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(54) **CHARGE PUMP**

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G05F 1/40 (2006.01)

(52) **U.S. Cl.** **363/60; 323/282**

(58) **Field of Classification Search** 363/59,

363/60; 323/282, 285; 327/535, 536

See application file for complete search history.

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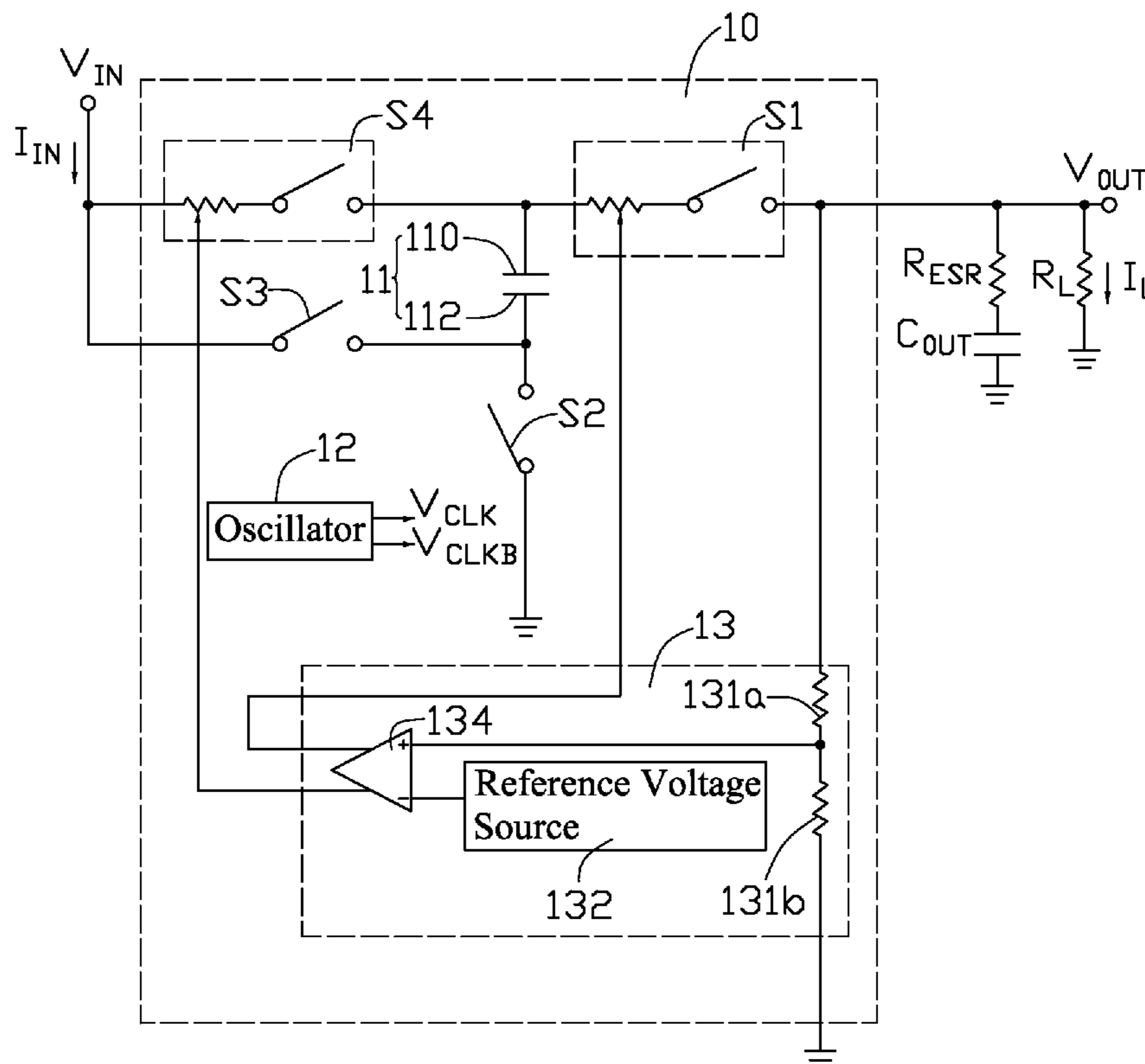
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(57) **ABSTRACT**

A charge pump includes a first capacitor, a first switch with adjustable on-state resistance, a second switch, a third switch, a fourth switch, a feedback loop, and an oscillator. The first switch is coupled between a first electrode of the first capacitor and an output node. The second switch is coupled between a second electrode of the capacitor and ground. The third switch is coupled between an input node and the second electrode of the capacitor. The fourth switch with adjustable on-state resistance is coupled between the input node and the first electrode of the capacitor. The feedback loop monitors a regulated voltage of the output node and generates a control signal to regulate resistances of the first, fourth switches. The oscillator generates a first and second pulse signals to switch the open and close states of the first, third switches and the second, fourth switches, respectively.

12 Claims, 6 Drawing Sheets



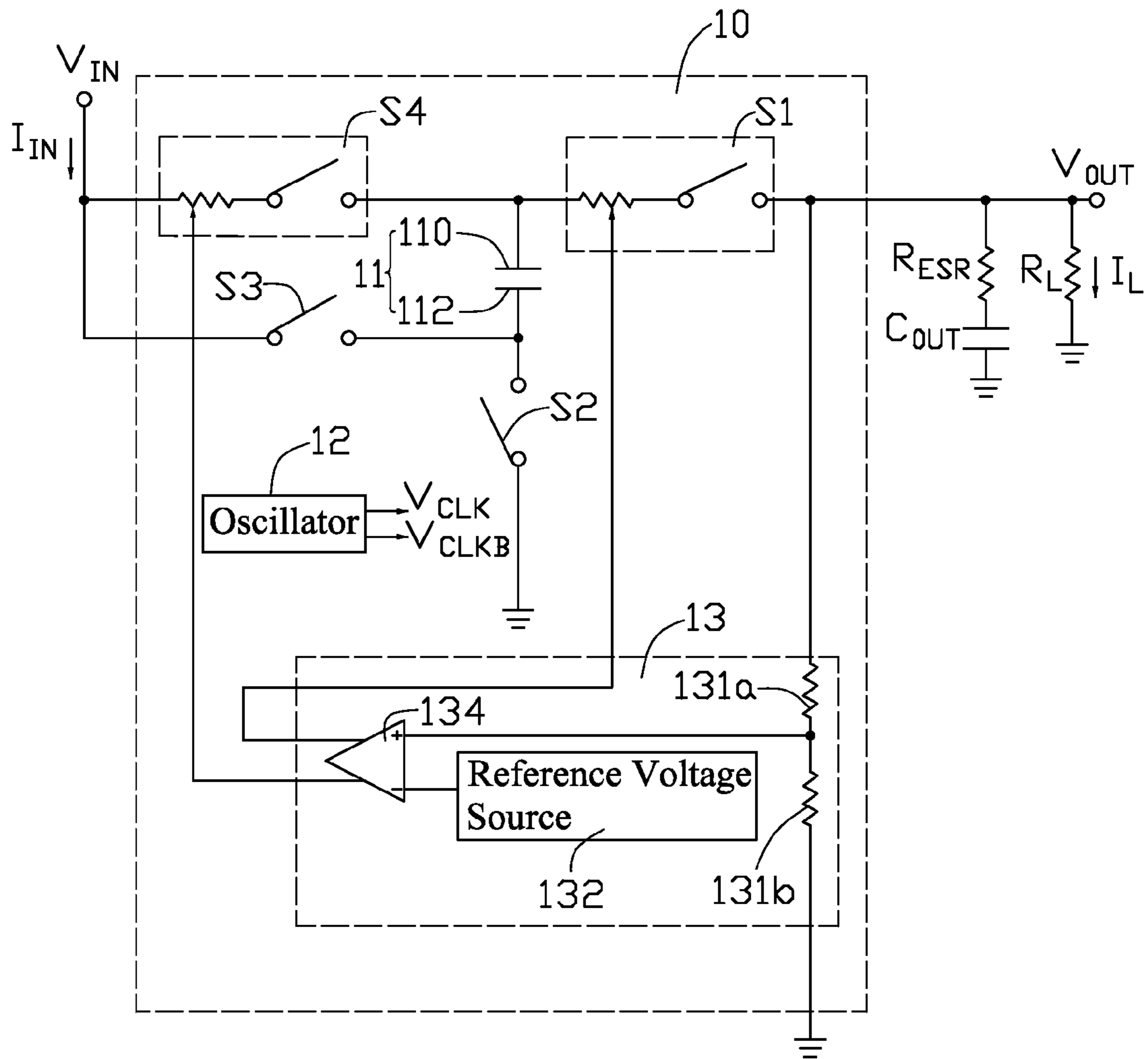


FIG. 1

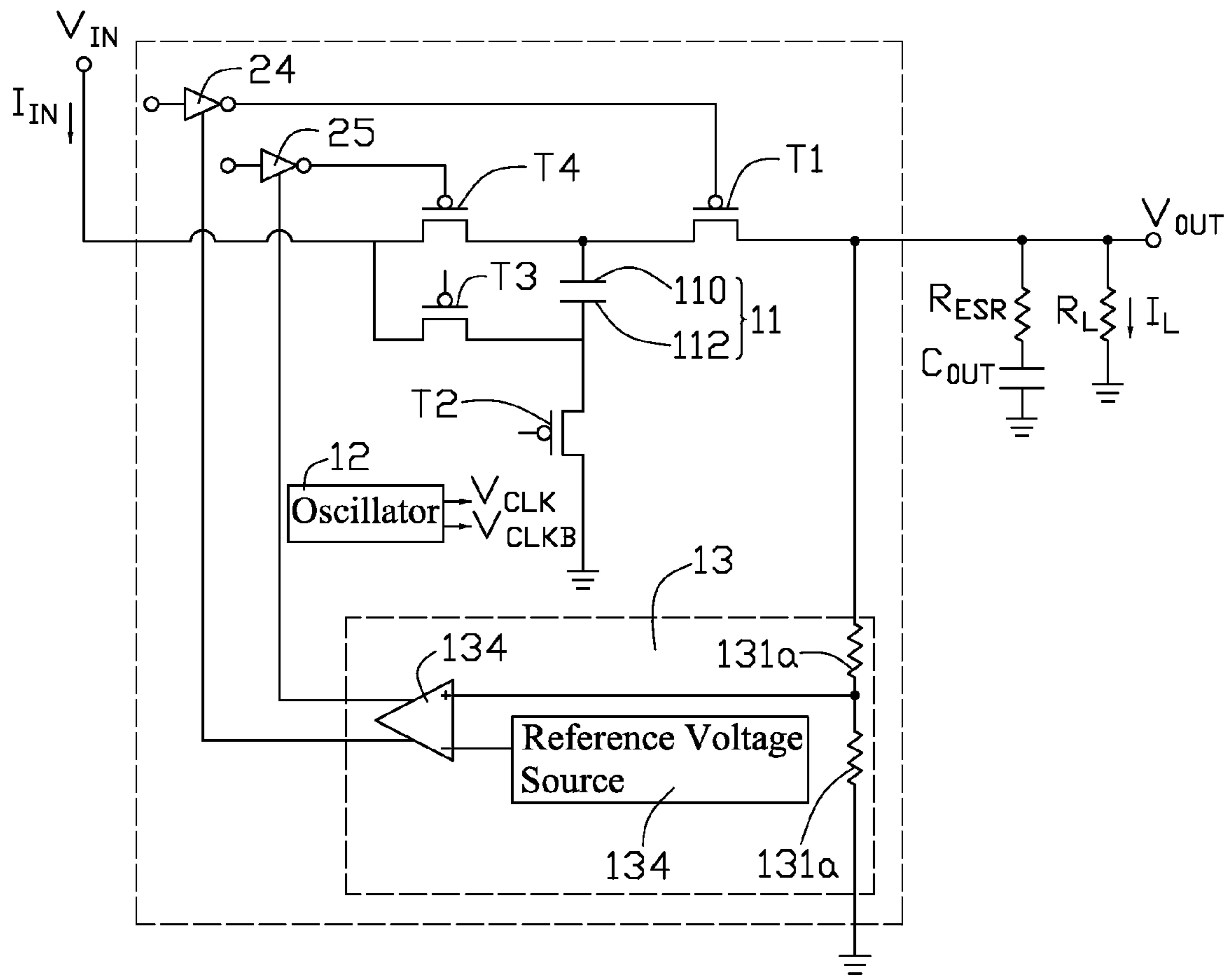


FIG. 2

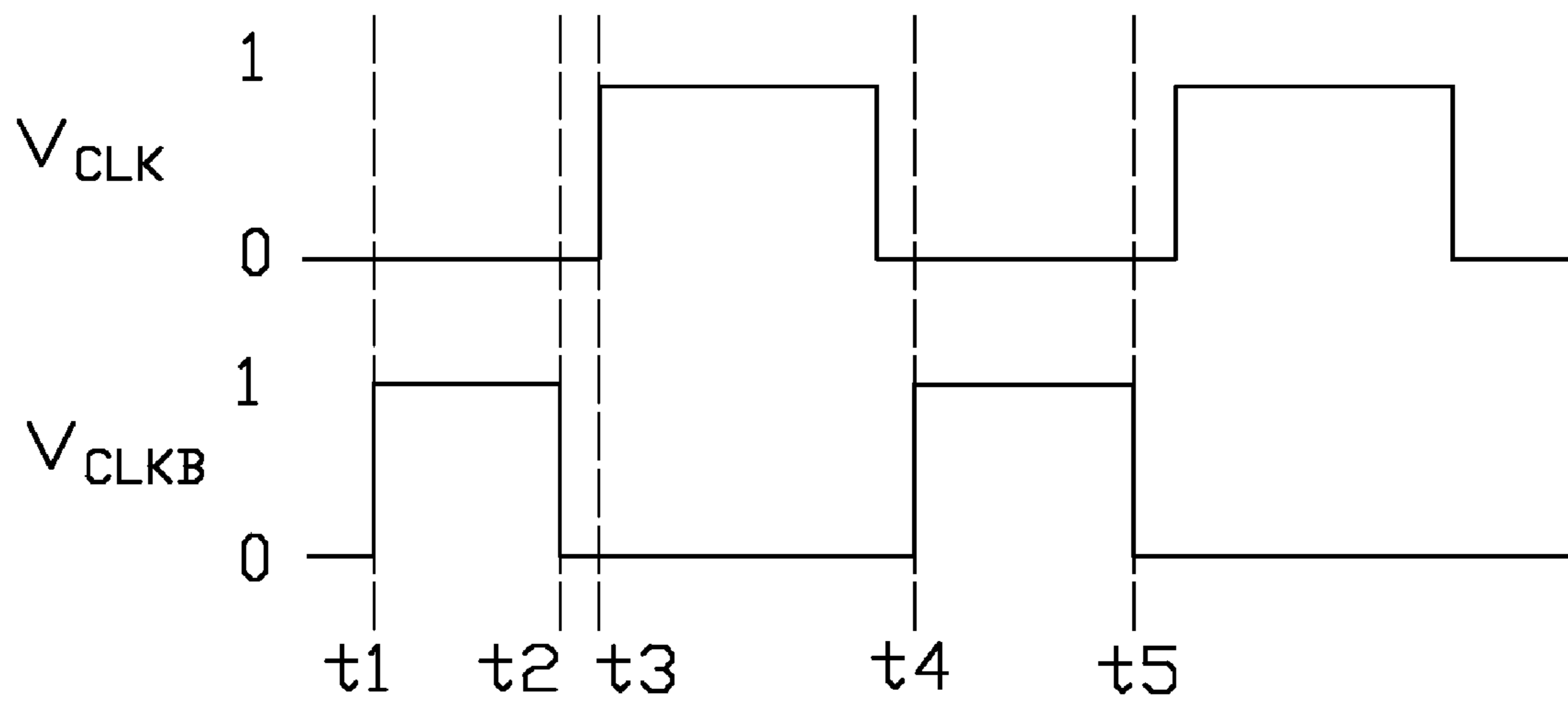


FIG. 3

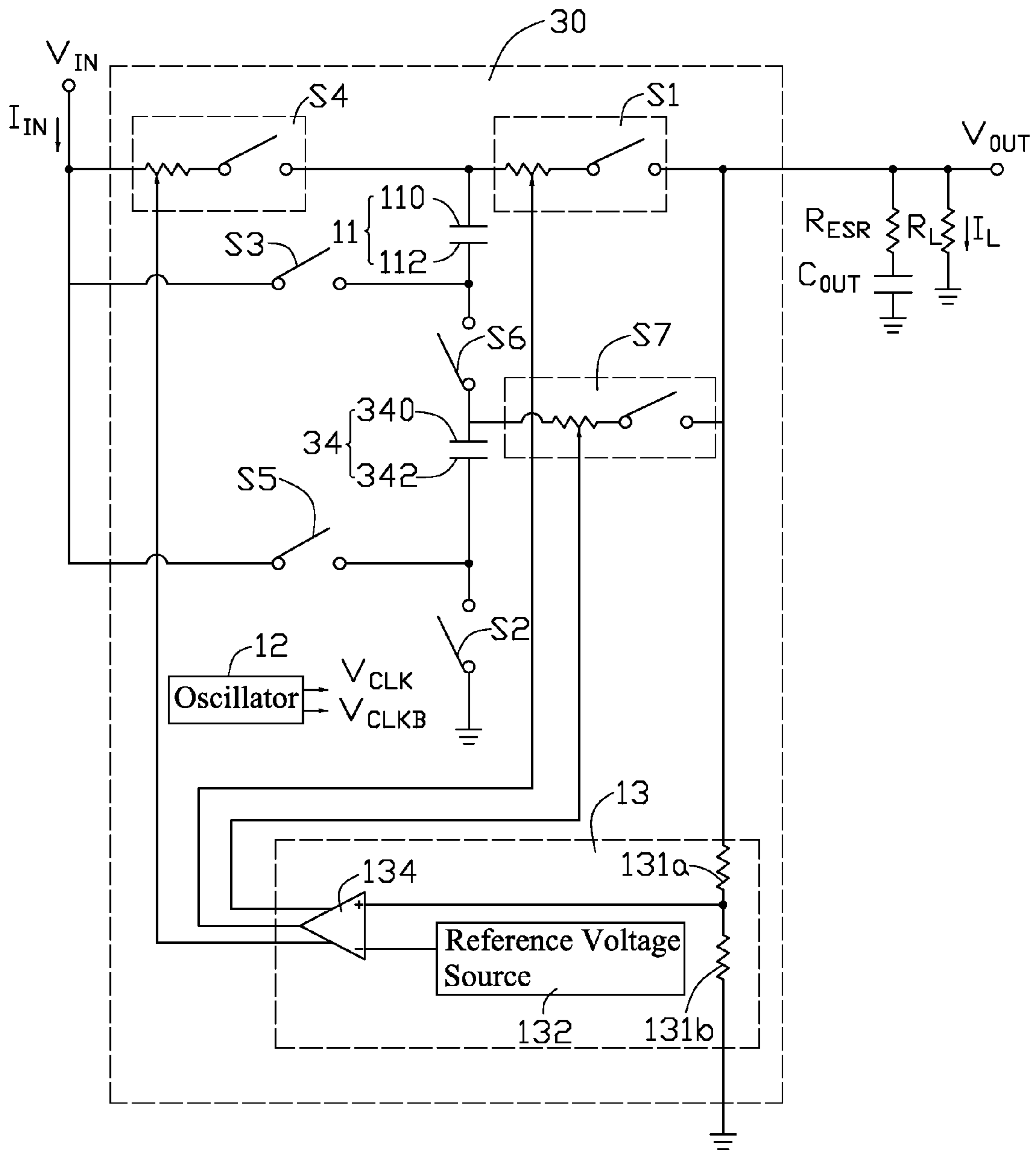


FIG. 4

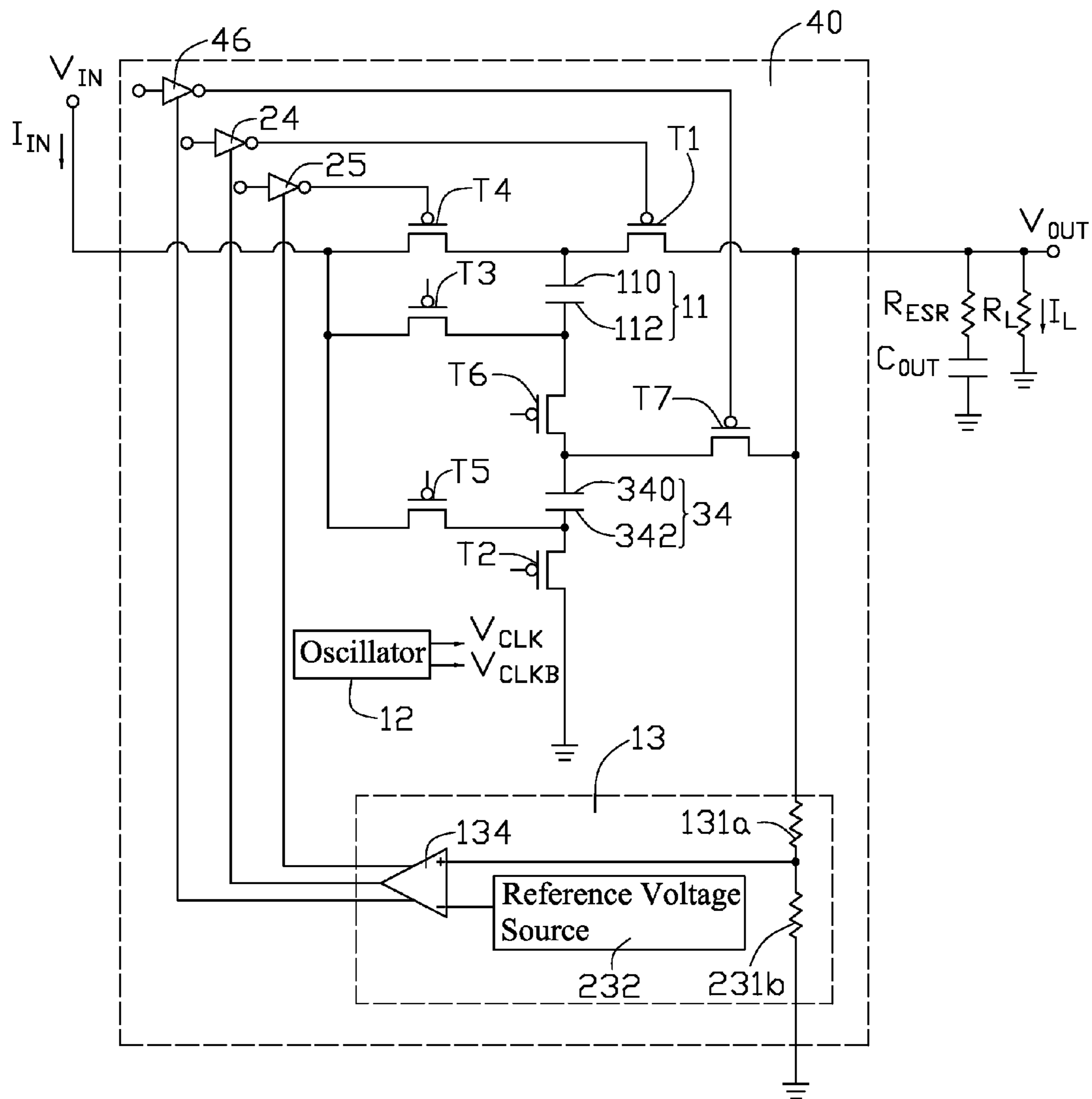


FIG. 5

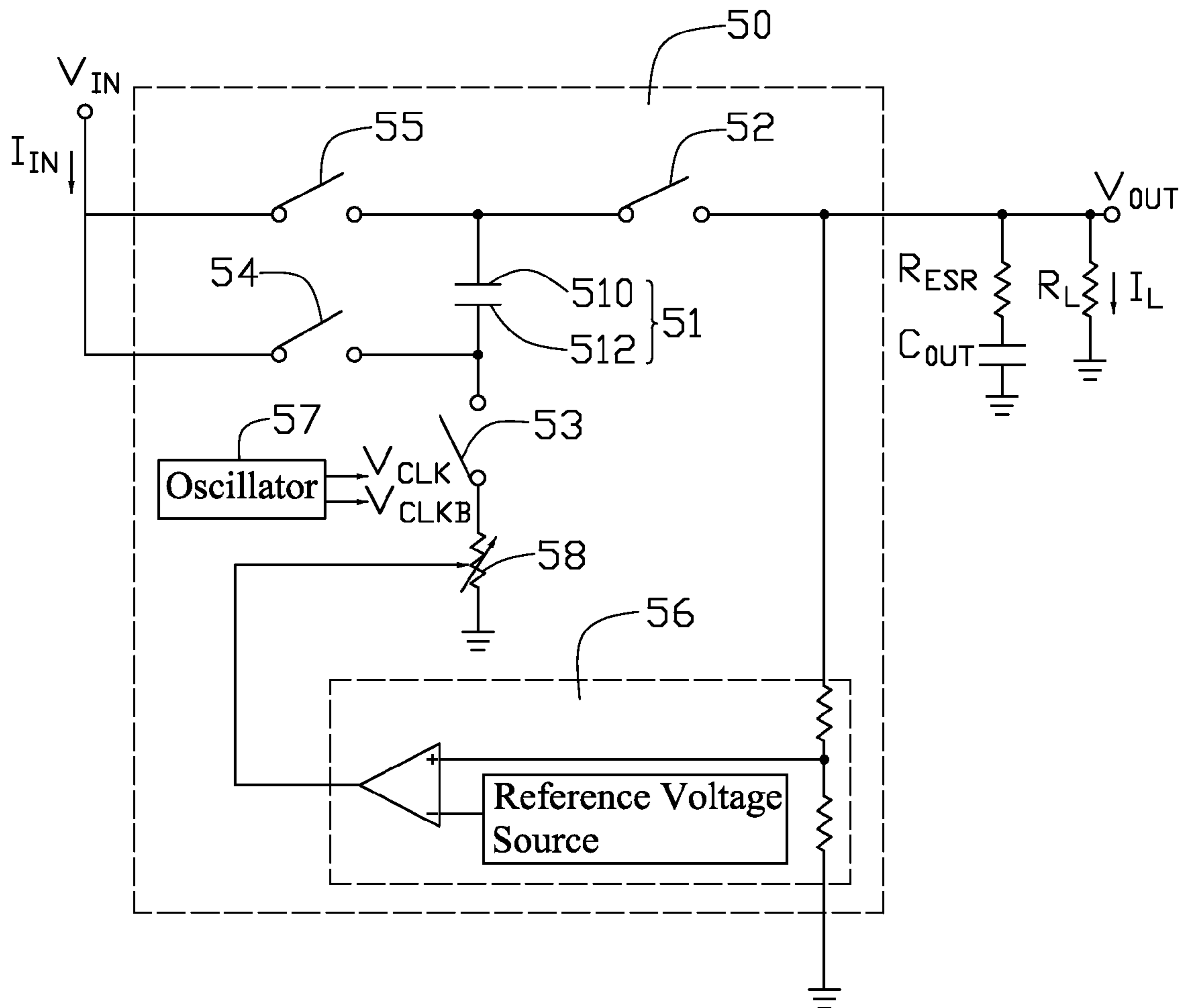


FIG. 6
(RELATED ART)

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CHARGE PUMP

BACKGROUND

1. Technical Field

The present invention relates to a charge pump, and particularly to a charge pump for converting a voltage at an input node into a regulated voltage and outputting the regulated voltage.

2. Discussion of Related Art

A charge pump is a kind of power supply circuit for converting a voltage at an input node into a regulated voltage and outputting the regulated voltage to loads. Referring to FIG. 6, a common charge pump **50** includes: a capacitor **51**, a first switch **52** coupled between a first electrode **510** of the capacitor **51** and an output node V_{OUT} , a second switch **53** and an adjustable resistor **58** both of which are coupled in series between a second electrode **512** of the capacitor **51** and ground, a third switch **54** coupled between the second electrode **512** of the capacitor **51** and an input node V_{IN} , a fourth switch **55** coupled between the first electrode **510** of the capacitor **51** and the input node V_{IN} , a feed back loop **56** for monitoring a voltage at the output node V_{OUT} , and an oscillator **57** for respectively controlling open/close states of the first switch **52**, the second switch **53**, the third switch **54** and the fourth switch **55**.

By switching open/close states of the switches, the charge pump **50** is alternatively charged and discharged, thereby the output node V_{OUT} outputs a voltage which is 2 times the voltage at the input node V_{IN} .

However, noises will be induced on incoming current I_{IN} during the switching of open/close states, which leads to fluctuation of the incoming current I_{IN} and instability of the outputting voltage.

Therefore, what is needed is a charge pump having reduced noises on the incoming current I_{IN} and stable outputting voltage.

SUMMARY

In one embodiment of the present invention, a charge pump for converting a voltage at an input node into a regulated voltage and outputting the regulated voltage at an output node is provided, the charge pump including: a first capacitor; a first switch with adjustable on-state resistance coupled between a first electrode of the first capacitor and the output node; a second switch coupled between a second electrode of the capacitor and ground; a third switch coupled between the input node and the second electrode of the capacitor, the third switch having an open and close state that matches the open and close state of the first switch, respectively; a fourth switch with adjustable on-state resistance coupled between the input node the first electrode of the capacitor, the fourth switch having an open and close state that matches the open and close state of the second switch, respectively; a feedback loop configured for monitoring the regulated voltage of the output node and thereby generating a control signal to regulate resistances of the first and the fourth switches; an oscillator for generating a first and second pulse signals to switch the open/close states of the first, third switches and the second, fourth switches, respectively.

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Detailed features of the present charge pump will become more apparent from the following detailed description and the accompanying drawings.

BRIEF DESCRIPTION OF THE DRAWINGS

Many aspects of the present charge pump can be better understood with reference to the following drawings. The components in the drawings are not necessarily drawn to scale, the emphasis instead being placed upon clearly illustrating the principles of the present charge pump. Moreover, in the drawings, like reference numerals designate corresponding parts throughout the several views, wherein:

FIG. 1 is a schematic view of a charge pump according to a first exemplary embodiment.

FIG. 2 is a schematic view of a charge pump according to a second exemplary embodiment.

FIG. 3 is a graph of input pulse signals for applying to the charge pump of FIG. 2.

FIG. 4 is a schematic view of a charge pump according to a third exemplary embodiment.

FIG. 5 is a schematic view of a charge pump according to a fourth exemplary embodiment.

FIG. 6 is a schematic view of a conventional charge pump.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

Reference will now be made to the drawings to describe the preferred embodiments of the charge pump, in detail.

Referring now particularly to FIG. 1, a charge pump **10** according to a first exemplary embodiment of the present invention is shown. The charge pump **10** comprises a capacitor **11**, an oscillator **12**, a first switch **S1**, a second switch **S2**, a third switch **S3**, a fourth switch **S4** and a feedback loop **13**.

The capacitor **11** comprises a first electrode **110** and a second electrode **12**.

The oscillator **12** is configured for generating pulse signals V_{CLK} and V_{CLKB} (see FIG. 3) which are used to respectively switch open/close states of the first switch **S1**, the second switch **S2**, the third switch **S3** and the fourth switch **S4**.

The first switch **S1** is coupled between the first electrode **110** of the capacitor **11** and the output node V_{OUT} . The first switch **S1** has an adjustable on-state resistance.

The second switch **S2** is coupled between the second electrode **112** of the capacitor **11** and the ground.

The third switch **S3** is coupled between the input node V_{IN} and the second electrode **112** of the capacitor **11**. The third switch **S3** has an open state and a close state that match the open and close states of the first switch **S1**, respectively.

The fourth switch **S4** is coupled between the input node V_{IN} and the first electrode **110** of the capacitor **11**. The fourth switch **S4** has an open state and a close state that match the open and close states of the second switch **S2**, respectively. The fourth switch **S4** has adjustable on-state resistance.

The feedback loop **13** is configured for adjusting the resistance of the first switch **S1** and the fourth switch **S4**, and therefore controlling the current I_{IN} to the capacitor **11** and the current I_L through a load R_L , thereby regulating the voltage V_{OUT} at the output node V_{OUT} . The feedback loop **13** includes resistors **131a**, **131b**, a reference voltage source **132** and a comparator **134**. The resistors **131a** and **131b** are connected in series and coupled between the output node V_{OUT} and ground. A non-inverting input port of the comparator **134** is connected to a node between the resistors **131a** and **131b**, and thereby a feedback voltage is provided to the non-inverting input port of the comparator **134**. The reference voltage

source **132** provides a reference voltage to an inverting input port of the comparator **134**. The comparator **134** compares the feedback voltage with the reference voltage, and thereby outputs a control signal at an output port to adjust the resistances of the first and fourth switches **S1**, **S4**.

When the V_{CLK} is LOW and the V_{CLKB} is HIGH, the second switch **S2** and the fourth switch **S4** are closed, the first switch **S1** and the third switch **S3** are opened. An inputting current I_{IN} flows from the input node V_{IN} to the capacitor **11**, and the capacitor **11** is charged thereby.

When the V_{CLK} is HIGH and the V_{CLKB} is LOW, the second switch **S2** and the fourth switch **S4** are opened, the first switch **S1** and the third switch **S3** are closed. An inputting current I_{IN} flows from the input node V_{IN} to the capacitor **11**, and the capacitor **11** discharges to the output node V_{OUT} .

When the current of the load I_L fluctuates to be less than an average value, redundant charges will be restored in the capacitor **11** and thereby make the output voltage V_{OUT} raise. The comparator **134** receives feedback voltage signals and generates a control signal to augment the resistance of the first switch **S1** in order to make the output voltage V_{OUT} reduce to the average value.

Referring now to FIG. 2, a charge pump **20** according to a second embodiment of the present invention is shown. The charge pump **20** includes a capacitor **11**, an oscillator **12**, a first field effect transistor **T1**, a second field effect transistor **T2**, a third field effect transistor **T3**, a fourth field effect transistor **T4**, a feedback loop **13**, and inverters **24** and **25**.

The oscillator **12** is configured for generating pulse signals V_{CLK} and V_{CLKB} (shown in FIG. 3) which are used to respectively switch open/close states of the first, third switches and the second, fourth switches. The pulse signals V_{CLK} and V_{CLKB} are out of phase with each other. Preferably, the pulse signals V_{CLK} and V_{CLKB} comprise brief blanking intervals when both pulse signals are low and all four switches are open (e.g., between times $t2$ and $t3$).

The first field effect transistor **T1** and the inverter **24** cooperatively form a switch with adjustable on-state resistance. The first field effect transistor **T1** can be a p-channel metal-oxide-semiconductor field effect transistor. A source electrode of the first field effect transistor **T1** is coupled to the first electrode **110**, and a drain electrode of the first field effect transistor **T1** is coupled to the output node V_{OUT} . A gate electrode of the first field effect transistor **T1** is coupled to an output port of the inverter **24**. The inverter **24** further comprises an input port and an enable port. The input port of the inverter **24** is coupled to the oscillator **12** for receiving the pulse signal V_{CLK} , and the enable port of the inverter **24** is coupled to the output port of the comparator **134** for receiving the control signal from the comparator **134**. It is to be noted that, the source electrode of the first field effect transistor **T1** can also be coupled to the output node V_{OUT} instead, and then the drain electrode of the first field effect transistor **T1** is correspondingly coupled to the first electrode **110**.

The second field effect transistor **T2** can be a p-channel metal-oxide-semiconductor field effect transistor. A source electrode of the second field effect transistor **T2** is coupled to the second electrode **112**, and a drain electrode of the second field effect transistor **T2** is coupled to the ground. A gate electrode of the second field effect transistor **T2** is coupled to the oscillator **12** for receiving the pulse signal V_{CLKB} . It is to be noted that, the source electrode of the second field effect transistor **T2** can also be coupled to the ground, and then the drain electrode of the second field effect transistor **T2** is correspondingly coupled to the second electrode **112**.

The third field effect transistor **T3** can be a p-channel metal-oxide-semiconductor field effect transistor. A source

electrode of the third field effect transistor **T3** is coupled to the input node V_{IN} , and a drain electrode of the third field effect transistor **T3** is coupled to the second electrode **112**. A gate electrode of the third field effect transistor **T3** is coupled to the oscillator **12** for receiving the pulse signal V_{CLK} . It is to be noted that, the source electrode of the third field effect transistor **T3** can also be coupled to the second electrode **112**, and then the drain electrode of the second field effect transistor **T3** is correspondingly coupled to the input node V_{IN} .

The fourth field effect transistor **T4** and the inverter **25** cooperatively form a switch with adjustable on-state resistance. The fourth field effect transistor **T4** can be a p-channel metal-oxide-semiconductor field effect transistor. A source electrode of the fourth field effect transistor **T4** is coupled to the input node V_{IN} , and a drain electrode of the fourth field effect transistor **T4** is coupled to the first electrode **110**. A gate electrode of the fourth field effect transistor **T4** is coupled to an output port of the inverter **25**. The inverter **25** further comprises an input port and an enable port. The input port of the inverter **25** is coupled to the oscillator **12** for receiving the pulse signal V_{CLKB} , and the enable port of the inverter **25** is coupled to the output port of the comparator **134** for receiving the control signal from the comparator **134**. It is to be noted that, the source electrode of the fourth field effect transistor **T4** can also be coupled to the first electrode **110**, and then the drain electrode of the fourth field effect transistor **T4** is correspondingly coupled to the input node V_{IN} .

The feedback loop **13** is configured for respectively outputting a controlling signal to the enable ports of the inverters **24** and **25**. Thereafter, the inverter **24** outputs a voltage signal to the gate electrode of the first field effect transistor **T1** to adjust the resistance between the drain electrode and the source electrode of the first field effect transistor **T1**, and the inverter **25** outputs a voltage signal to the gate electrode of the fourth field effect transistor **T4** to adjust the resistance between the drain electrode and the source electrode of the fourth field effect transistor **T4**. Therefore, the current I_{IN} flowing to the capacitor **11** and the current I_L flowing through the load R_L are controlled indirectly by the feedback loop **13**, and then the voltage V_{OUT} at the output node V_{OUT} is regulated. The feedback loop includes resistors **131a**, **131b**, a reference voltage source **132** and a comparator **134**. The resistors **131a** and **131b** are connected in series and coupled between the output node V_{OUT} and ground, and thereby provide a feedback voltage to the non-inverting input port of the comparator **134**. The reference voltage source **132** provides a reference voltage to an inverting input port of the comparator **134**. The comparator **134** compares the feedback voltage with the reference voltage, and thereafter outputs a control signal to the enable ports of inverters **24** and **25**.

Referring to FIG. 3, the working process of charge pump **20** is described as follow:

Between time $t1$ and $t2$, V_{CLK} is LOW and the V_{CLKB} is HIGH. The first field effect transistor **T1** and the third field effect transistor **T3** are OFF, and the second field effect transistor **T2** and the fourth field effect transistor **T4** are ON. The input current I_{IN} flows from the input node V_{IN} charging up the capacitor **11**, and a voltage of the capacitor **11** equal to a voltage at the input node V_{IN} .

Between time $t2$ and $t3$, both of V_{CLK} and V_{CLKB} are LOW. The first field effect transistor **T1**, the second field effect transistor **T2**, the third field effect transistor **T3** and the fourth field effect transistor **T4** are OFF.

Between time $t3$ and $t4$, V_{CLK} is HIGH and the V_{CLKB} is LOW. The first field effect transistor **T1** and the third field effect transistor **T3** are ON, and the second field effect transistor **T2** and the fourth field effect transistor

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T4 are OFF. Current flows from input node V_{IN} through the third field effect transistor T3 to capacitor 11, and from capacitor 11 through the first field effect transistor T1 to output node V_{OUT} .

Between time t2 and t3, both of V_{CLK} and V_{CLKB} are LOW.

The first field effect transistor T1, the second field effect transistor T2, the third field effect transistor T3 and the fourth field effect transistor T4 are OFF.

By alternatively controlling the first field effect transistor T1, the second field effect transistor T2, the third field effect transistor T3 and the fourth field effect transistor T4 to ON and OFF, the capacitor 11 is alternatively charged and discharged, thereby the output node V_{OUT} outputs a voltage equal to a sum of the voltage at the input node V_{IN} and the voltage of the capacitor 11, thereby the voltage at the output node V_{OUT} is 2 times the voltage at the input node V_{IN} to the load.

When the current through load I_L is less than the average output, charge stored in the capacitor 11 will increase and the voltage at the output node V_{OUT} will raise, further lead to rise of the feedback voltage provided to the comparator 134. The comparator 134 compares the feedback voltage with the reference voltage, and thereafter outputs a control signal to the enable ports of inverters 24 and 25, so as to respectively raise the resistance between the drain electrode and the source electrode of the first field effect transistor T1, and the resistance between the drain electrode and the source electrode of the fourth field effect transistor T4 by controlling the gate electrodes of the first field effect transistor T1 and the fourth field effect transistor T4, thereby bring down the output voltage at the output node V_{OUT} .

Similarly, when the current through load I_L is greater than the average output, the charge pump 20 will bring down the resistance between the drain electrode and the source electrode of the first field effect transistor T1, and the resistance between the drain electrode and the source electrode of the fourth field effect transistor T4 by controlling the gate electrodes of the first field effect transistor T1 and the fourth field effect transistor T4, thereby raise the output voltage at the output node V_{OUT} .

Referring now to FIG. 4, where a charge pump 30 according to a third embodiment of the present invention is shown. The configuration of charge pump 30 is generally similar to the above-mentioned charge pump 10. What's different is that, the charge pump 30 further comprises a fifth switch S5, a sixth switch S6, a seventh switch S7 and capacitor 34.

The capacitor 34 includes a first electrode 340 and a second electrode 342. The capacitor 34 is coupled to the sixth switch S6 in series and disposed between the capacitor 11 and second switch S2. The fifth switch S5 is coupled between the input node V_{IN} and the second electrode 342 of the capacitor 34. The seventh switch S7 is coupled between the first electrode 340 of the capacitor 34 and the output node V_{OUT} . The fifth switch S5 and the seventh switch S7 have an open state and a close state that can be switched by pulse signal V_{CLK} of oscillator 12. The sixth switch S6 have an open state and a close state that can be switched by pulse signal V_{CLKB} of oscillator 12. When switches S2, S4, S6 are closed and switches S1, S3, S5, S7 are opened, the capacitors 11 and 34 will be charged and each of the capacitors 11 and 34 has a voltage 0.5 times the voltage at the input node V_{IN} . When switches S2, S4, S6 are opened and switches S1, S3, S5, S7 are closed, the capacitors 11 and 34 will be discharged. Thereby, there will be a voltage at the output node V_{OUT} that equal to a sum of the voltage at the input node V_{IN} and the voltage of the capacitor 11 (or the voltage of the capacitor 34), thereby the voltage at the output node V_{OUT} is 1.5 times the

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voltage at the input node V_{IN} to the load. It is to be noted that, the location of the switch S6 and the capacitor 34 can be interchanged without interfering the normal working of the charging pump 30.

Referring now to FIG. 5, where a charge pump 40 according to a fourth embodiment of the present invention is shown. The configuration of charge pump 40 is generally similar to the above-mentioned the charge pump 20. The difference between the charge pump 20 and 40 is that, the charge pump 40 further comprises a fifth field effect transistor T5, a sixth field effect transistor T6, a seventh field effect transistor T7, a capacitor 34 with a first electrode 340 and a second electrode 342, and an inverter 46.

The fifth field effect transistor T5 can be a p-channel metal-oxide-semiconductor field effect transistor. A source electrode of the fifth field effect transistor T5 is coupled to the second electrode 342 of the capacitor 34, and a drain electrode of the fifth field effect transistor T5 is coupled to the input node V_{IN} . A gate electrode of the fifth field effect transistor T5 is coupled to the oscillator 12 for receiving the pulse signal V_{CLK} . It is to be noted that, the source electrode of the fifth field effect transistor T5 can also be coupled to the input node V_{IN} , and then the drain electrode of the fifth field effect transistor T5 is correspondingly coupled to the second electrode 342 of the capacitor 34.

The sixth field effect transistor T6 can be a p-channel metal-oxide-semiconductor field effect transistor. A source electrode of the sixth field effect transistor T6 is coupled to one of the second electrode 112 of the capacitor 11 and the first electrode 340 of the capacitor 34, and a drain electrode of the sixth field effect transistor T6 is coupled to the other. A gate electrode of the sixth field effect transistor T6 is coupled to the oscillator 12 for receiving the pulse signal V_{CLKB} .

The seventh field effect transistor T7 and the inverter 46 cooperatively form a switch with adjustable on-state resistance. The seventh field effect transistor T7 can be a p-channel metal-oxide-semiconductor field effect transistor. A source electrode of the seventh field effect transistor T7 is coupled between the sixth field effect transistor T6 and the output node V_{OUT} . A gate electrode of the seventh field effect transistor T7 is coupled to an output port of the inverter 46. The inverter 46 further comprises an input port and an enable port. The input port of the inverter 46 is coupled to the oscillator 12 for receiving the pulse signal V_{CLK} , and the enable port of the inverter 46 is coupled to the output port of the comparator 134 for receiving the control signal from the comparator 134.

The charge pumps 10, 20, 30 and 40 monitor voltage changes and generate controlling signals by the feedback loop 13, thereafter regulating resistance of the switches with adjustable on-state resistance and further regulating voltage at the output node V_{OUT} . The above-mentioned charge pumps have function of regulating a fluctuation of the incoming current I_{IN} and stabilizing the outputting voltage. The switches with adjustable on-state resistance also make the above-mentioned charge pumps have small scale and low cost.

Finally, it is to be understood that the above-described embodiments are intended to illustrate rather than limit the invention. Variations may be made to the embodiments without departing from the spirit of the invention as claimed. The above-described embodiments illustrate the scope of the invention but do not restrict the scope of the invention.

What is claimed is:

1. A charge pump for converting a voltage at an input node into a regulated voltage and outputting the regulated voltage at an output node, the charge pump comprising:

- a first capacitor;
 - a first switch with adjustable on-state resistance coupled between a first electrode of the first capacitor and the output node;
 - a second switch coupled between a second electrode of the capacitor and ground;
 - a third switch coupled between the input node and the second electrode of the capacitor, the third switch having an open state and a close state that match the open and close states of the first switch, respectively;
 - a fourth switch with adjustable on-state resistance coupled between the input node and the first electrode of the capacitor, the fourth switch having an open state and a close state that match the open and close states of the second switch, respectively;
 - a feedback loop configured for monitoring the regulated voltage of the output node; and
 - an oscillator for generating a first and a second pulse signals to switch the open and close states of the first, third switches and the second, fourth switches, respectively;
- wherein the first and the fourth switches each comprises an inverter and a field effect transistor; an input port of the inverter is connected to the oscillator to receive the first or second pulse signal, an enable port of the inverter is connected to an output port of the comparator, an output port of the inverter is connected to a gate electrode of the field effect transistor; the field effect transistor of the first switch comprises a source electrode connected to the first electrode of the first capacitor, and a drain electrode connected to the output node; the fourth switch comprises a source electrode connected to the second electrode of the first capacitor; and a drain electrode connected to ground.

2. The charge pump according to claim 1, wherein the feedback loop comprises a first resistor, a second resistor, a reference voltage source and a comparator having a non-inverting input port and an inverting input port, the first and second resistors provide a feedback voltage at the non-inverting input port, the reference voltage source provides a reference voltage at the inverting input port, the comparator compares the feedback voltage and the reference voltage and thereby generates a control signal to regulate resistances of the first and the fourth switches.

3. The charge pump according to claim 2, wherein the first resistor and the second resistor are connected in series and coupled between the output node and ground, the non-inverting input port of the comparator is connected to a node between the first resistor and the second resistor.

4. The charge pump according to claim 1, wherein the field effect transistors are p-channel metal-oxide-semiconductor field effect transistors.

5. The charge pump according to claim 1, wherein the charge pump further comprises a second capacitor, a fifth switch, a sixth switch and a seventh switch, the second capacitor and the sixth switch are connected in series and coupled between the first capacitor and the second switch, the fifth switch is coupled between the input node and a second electrode of the second capacitor, the open and close states of the fifth and seventh switches can be controlled by the first pulse signal, the seventh switch has an adjustable on-state resistance and is coupled between the output node and a node between the first and second capacitor, the sixth switch has an

adjustable on-state resistance and the open and close states of the sixth switch can be controlled by the second pulse signal.

6. The charge pump according to claim 5, wherein the seventh switch comprises an inverter and a field effect transistor, an input port of the inverter is connected to the oscillator to receive the first pulse signal, an enable port of the inverter is connected to an output port of the comparator, an output port of the inverter is connected to a gate electrode of the field effect transistor, the field effect transistor of the seventh switch comprises a source electrode and a drain electrode, the source electrode of the field effect transistor is connected to the first electrode of the second capacitor and the drain electrode of the field effect transistor is connected to the output node.

7. The charge pump according to claim 6, wherein the field effect transistors are p-channel metal-oxide-semiconductor field effect transistors.

8. A charge pump for converting a voltage at an input node into a regulated voltage and outputting the regulated voltage at an output node, the charge pump comprising:

- a first capacitor;
 - a first switch with adjustable on-state resistance coupled between a first electrode of the first capacitor and the output node;
 - a second switch coupled between a second electrode of the capacitor and ground;
 - a third switch coupled between the input node and the second electrode of the capacitor, the third switch having an open state and a close state that match the open and close states of the first switch, respectively;
 - a fourth switch with adjustable on-state resistance coupled between the input node and the first electrode of the capacitor, the fourth switch having an open state and a close state that match the open and close states of the second switch, respectively;
 - a feedback loop configured for monitoring the regulated voltage of the output node;
 - an oscillator for generating a first and a second pulse signals to switch the open and close states of the first, third switches and the second, fourth switches, respectively;
 - a second capacitor,
 - a fifth switch coupled between the input node and a second electrode of the second capacitor;
 - a sixth switch having an adjustable on-state resistance, the second capacitor and the sixth switch being connected in series and coupled between the first capacitor and the second switch; and
 - a seventh switch coupled between the output node and a node between the first and second capacitor, the seventh switch having an adjustable on-state resistance;
- wherein the open and close states of the fifth and seventh switches can be controlled by the first pulse signal, and the open and close states of the sixth switch can be controlled by the second pulse signal.

9. The charge pump according to claim 8, wherein the seventh switch comprises an inverter and a field effect transistor, an input port of the inverter is connected to the oscillator to receive the first pulse signal, an enable port of the inverter is connected to an output port of the comparator, an output port of the inverter is connected to a gate electrode of the field effect transistor, the field effect transistor of the seventh switch comprises a source electrode and a drain electrode, the source electrode of the field effect transistor is connected to the first electrode of the second capacitor and the drain electrode of the field effect transistor is connected to the output node.

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10. The charge pump according to claim **9**, wherein the field effect transistors are p-channel metal-oxide-semiconductor field effect transistors.

11. The charge pump according to claim **8**, wherein the feedback loop comprises a first resistor, a second resistor, a reference voltage source and a comparator having a non-inverting input port and an inverting input port, the first and second resistors provide a feedback voltage at the non-inverting input port, the reference voltage source provides a reference voltage at the inverting input port, the comparator com-

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pares the feedback voltage and the reference voltage and thereby generates a control signal to regulate resistances of the first and the fourth switches.

12. The charge pump according to claim **11**, wherein the first resistor and the second resistor are connected in series and coupled between the output node and ground, the non-inverting input port of the comparator is connected to a node between the first resistor and the second resistor.

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